Product datasheet Characteristics

TM221C24R controller M221 24 IO relay



Price*: 204.82 GBP



Main

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Range of product	Modicon M221	
Product or component type	Logic controller	<u> </u>
[Us] rated supply voltage	100240 V AC	
Discrete input number	14 discrete input conforming to IEC 61131-2 Type 1	
Analogue input number	2 at input range: 010 V	±0
Discrete output type	Relay normally open	
Discrete output number	10 relay	
Discrete output voltage	5125 V DC 5250 V AC	viiit Viideliili
Discrete output current	2 A	v

Complementary

Discrete I/O number	24	9
Number of I/O expansion module	<= 7 for transistor output <= 7 for relay output	
Supply voltage limits	85264 V	<u></u>
Network frequency	50/60 Hz	
Inrush current	<= 40 A	
Power consumption in VA	<= 55 VA at 100240 V with max number of I/O expansion module <= 32 VA at 100240 V without I/O expansion module	
Power supply output current	0.52 A at 5 V for expansion bus 0.16 A at 24 V for expansion bus	de de de
Discrete input logic	Sink or source (positive/negative)	.= .= .= .=
Discrete input voltage	24 V	
Discrete input voltage type	DC	
Analogue input resolution	10 bits	<u> </u>
LSB value	10 mV	
Conversion time	1 ms per channel + 1 controller cycle time for analog input	
Permitted overload on inputs	+/- 30 V DC for analog input with 5 min maximum	

	+/- 13 V DC for analog input permanent
Voltage state 1 guaranteed	>= 15 V for input
Voltage state 0 guaranteed	<= 5 V for input
Discrete input current	7 mA for discrete input 5 mA for fast input
Input impedance	4.9 kOhm for fast input 3.4 kOhm for discrete input 100 kOhm for analog input
Response time	10 ms turn-on operation for output 35 μs turn-off operation for input; I2I5 terminal 10 ms turn-off operation for output 5 μs turn-on operation for fast input; I0, I1, I6, I7 terminal 35 μs turn-on operation for input; other terminals terminal 5 μs turn-off operation for fast input; I0, I1, I6, I7 terminal 100 μs turn-off operation for input; other terminals terminal
Configurable filtering time	0 ms for input 12 ms for input 3 ms for input
Output voltage limits	125 V DC 277 V AC
Current per output common	4 A at COM 2 termnal 7 A at COM 0 termnal 7 A at COM 1 termnal
Absolute accuracy error	+/- 1 % of full scale for analog input
Electrical durability	Inductive AC-15, (cos phi = 0.35) 240 V / 120 VA : 100000 cycles Resistive DC-12, 24 V / 48 W : 100000 cycles Resistive AC-12, 120 V / 240 VA : 100000 cycles Inductive AC-15, (cos phi = 0.35) 240 V / 36 VA : 300000 cycles Resistive AC-12, 120 V / 80 VA : 300000 cycles Inductive (L/R = 7 ms) DC-13, 24 V / 24 W : 100000 cycles Resistive DC-12, 24 V / 16 W : 300000 cycles Inductive (L/R = 7 ms) DC-13, 24 V / 7.2 W : 300000 cycles Inductive (L/R = 7 ms) DC-13, 24 V / 7.2 W : 300000 cycles Inductive AC-14, (cos phi = 0.7) 240 V / 240 VA : 100000 cycles Inductive AC-15, (cos phi = 0.35) 120 V / 60 VA : 100000 cycles Inductive AC-14, (cos phi = 0.7) 240 V / 72 VA : 300000 cycles Inductive AC-15, (cos phi = 0.35) 120 V / 18 VA : 300000 cycles Resistive AC-12, 240 V / 480 VA : 100000 cycles Inductive AC-14, (cos phi = 0.7) 120 V / 120 VA : 100000 cycles Resistive AC-12, 240 V / 160 VA : 300000 cycles Inductive AC-14, (cos phi = 0.7) 120 V / 36 VA : 300000 cycles
Switching frequency	20 switching operations/minute with maximum load
Switching frequency Mechanical durability	20 switching operations/minute with maximum load >= 20000000 cycles for relay output
Mechanical durability	>= 20000000 cycles for relay output
Mechanical durability Minimum load	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output
Mechanical durability Minimum load Protection type Reset time Memory capacity	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM
Mechanical durability Minimum load Protection type Reset time Memory capacity Data backed up	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data
Mechanical durability Minimum load Protection type Reset time Memory capacity	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data 2 GB SD card optional
Mechanical durability Minimum load Protection type Reset time Memory capacity Data backed up Data storage equipment Battery type	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data 2 GB SD card optional BR2032 lithium non-rechargeable, battery life: 4 yr
Mechanical durability Minimum load Protection type Reset time Memory capacity Data backed up Data storage equipment Battery type Backup time	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data 2 GB SD card optional BR2032 lithium non-rechargeable, battery life: 4 yr 1 year at 25 °C by interruption of power supply
Mechanical durability Minimum load Protection type Reset time Memory capacity Data backed up Data storage equipment Battery type Backup time Execution time for 1 KInstruction	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data 2 GB SD card optional BR2032 lithium non-rechargeable, battery life: 4 yr 1 year at 25 °C by interruption of power supply 0.3 ms for event and periodic task
Mechanical durability Minimum load Protection type Reset time Memory capacity Data backed up Data storage equipment Battery type Backup time Execution time for 1 KInstruction Execution time per instruction	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data 2 GB SD card optional BR2032 lithium non-rechargeable, battery life: 4 yr 1 year at 25 °C by interruption of power supply 0.3 ms for event and periodic task 0.2 µs Boolean
Mechanical durability Minimum load Protection type Reset time Memory capacity Data backed up Data storage equipment Battery type Backup time Execution time for 1 KInstruction Execution time per instruction Exct time for event task	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data 2 GB SD card optional BR2032 lithium non-rechargeable, battery life: 4 yr 1 year at 25 °C by interruption of power supply 0.3 ms for event and periodic task 0.2 µs Boolean 60 µs response time
Mechanical durability Minimum load Protection type Reset time Memory capacity Data backed up Data storage equipment Battery type Backup time Execution time for 1 KInstruction Execution time per instruction	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data 2 GB SD card optional BR2032 lithium non-rechargeable, battery life: 4 yr 1 year at 25 °C by interruption of power supply 0.3 ms for event and periodic task 0.2 µs Boolean
Mechanical durability Minimum load Protection type Reset time Memory capacity Data backed up Data storage equipment Battery type Backup time Execution time for 1 KInstruction Execution time per instruction Exct time for event task	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data 2 GB SD card optional BR2032 lithium non-rechargeable, battery life: 4 yr 1 year at 25 °C by interruption of power supply 0.3 ms for event and periodic task 0.2 µs Boolean 60 µs response time 255 %TM timers 512 %M memory bits 512 %KW constant words 255 %C counters
Mechanical durability Minimum load Protection type Reset time Memory capacity Data backed up Data storage equipment Battery type Backup time Execution time for 1 KInstruction Execution time per instruction Exct time for event task Maximum size of object areas	>= 20000000 cycles for relay output 1 mA at 5 V DC for relay output Without protection at 5 A 1 s 256 kB for user application and data RAM with 10000 instructions 256 kB for internal variables RAM 256 kB built-in flash memory for backup of application and data 2 GB SD card optional BR2032 lithium non-rechargeable, battery life: 4 yr 1 year at 25 °C by interruption of power supply 0.3 ms for event and periodic task 0.2 µs Boolean 60 µs response time 255 %TM timers 512 %M memory bits 512 %KW constant words 255 %C counters 8000 %MW memory words

Control signal type	Single phase A/B Pulse/Direction	
tegrated connection type	USB port with connector mini B USB 2.0 Non isolated serial link "serial 1" with connector RJ45 and interface RS485 Non isolated serial link "serial 2" with connector RJ45 and interface RS232/RS485	
Supply	Serial serial link supply at 5 V 200 mA	
Transmission rate	1.2115.2 kbit/s (115.2 kbit/s by default) for bus length of 15 m - communication protocol: RS48! 1.2115.2 kbit/s (115.2 kbit/s by default) for bus length of 3 m - communication protocol: RS232 480 Mbit/s - communication protocol: USB	
Communication port protocol	USB port : USB protocol - SoMachine-Network Non isolated serial link : Modbus protocol master/slave - RTU/ASCII or SoMachine-Network	
Local signalling	1 LED green for SD card access (SD) 1 LED red for BAT 1 LED green for SL1 1 LED green for SL2 1 LED per channel green for I/O state 1 LED red for module error (ERR) 1 LED green for PWR 1 LED green for RUN	
Electrical connection	Mini B USB 2.0 connector for a programming terminal Terminal block, 3 terminal(s) for connecting the 24 V DC power supply Connector, 4 terminal(s) for analogue inputs Removable screw terminal block for inputs Removable screw terminal block for outputs	
Cable distance between devices	Shielded cable: 10 m for fast input Unshielded cable: 30 m for output Unshielded cable: 30 m for digital input Unshielded cable: 1 m for analog input	
Insulation	2300 V AC between output and internal logic Non-insulated between analogue inputs 500 V AC between input and internal logic Non-insulated between analogue input and internal logic 1500 V AC between supply and ground 500 V AC between sensor power supply and ground 500 V AC between input and ground 1500 V AC between output and ground 2300 V AC between supply and internal logic 500 V AC between sensor power supply and internal logic 500 V AC between Ethernet terminal and internal logic 2300 V AC between supply and sensor power supply	
Marking	CE	
Sensor power supply	24 V DC at 250 mA supplied by the controller	
Mounting support	Top hat type TH35-15 rail conforming to IEC 60715 Top hat type TH35-7.5 rail conforming to IEC 60715 Plate or panel with fixing kit	
Height	90 mm	
Depth	70 mm	
Width	110 mm	
Product weight	0.395 kg	

Environment

Standards	EN/IEC 61010-2-201 EN/IEC 60664-1 EN/IEC 61131-2
Product certifications	CULus RCM DNV-GL LR IACS E10 EAC ABS CSA
Environmental characteristic	Ordinary and hazardous location
Resistance to electrostatic discharge	4 kV on contact conforming to EN/IEC 61000-4-2 8 kV in air conforming to EN/IEC 61000-4-2

Resistance to electromagnetic fields	10 V/m (80 MHz1 GHz) conforming to EN/IEC 61000-4-3 3 V/m (1.4 GHz2 GHz) conforming to EN/IEC 61000-4-3 1 V/m (22.7 GHz) conforming to EN/IEC 61000-4-3
Resistance to magnetic fields	30 A/m 50/60 Hz conforming to EN/IEC 61000-4-8
Resistance to fast transients	2 kV for power lines conforming to EN/IEC 61000-4-4 2 kV for relay output conforming to EN/IEC 61000-4-4 1 kV for Ethernet line conforming to EN/IEC 61000-4-4 1 kV for serial link conforming to EN/IEC 61000-4-4 1 kV for I/O conforming to EN/IEC 61000-4-4
Surge withstand	2 kV for power lines (AC) in common mode conforming to EN/IEC 61000-4-5 2 kV for relay output in common mode conforming to EN/IEC 61000-4-5 1 kV for I/O in common mode conforming to EN/IEC 61000-4-5 1 kV for shielded cable in common mode conforming to EN/IEC 61000-4-5 0.5 kV for power lines (DC) in differential mode conforming to EN/IEC 61000-4-5 1 kV for power lines (AC) in differential mode conforming to EN/IEC 61000-4-5 1 kV for relay output in differential mode conforming to EN/IEC 61000-4-5 0.5 kV for power lines (DC) in common mode conforming to EN/IEC 61000-4-5
Resistance to conducted disturbances	10 Vrms (0.1580 MHz) conforming to EN/IEC 61000-4-6 3 Vrms (0.180 MHz) conforming to Marine specification (LR, ABS, DNV, GL) 10 Vrms (spot frequency (2, 3, 4, 6.2, 8.2, 12.6, 16.5, 18.8, 22, 25 MHz)) conforming to Marine specification (LR, ABS, DNV, GL)
Electromagnetic emission	Conducted emissions conforming to EN/IEC 55011 power lines (AC), 0.150.5 MHz: 79 dB μ V/m QP/66 dB μ V/m AV Conducted emissions conforming to EN/IEC 55011 power lines (AC), 0.5300 MHz: 73 dB μ V/m QP/60 dB μ V/m AV Conducted emissions conforming to EN/IEC 55011 power lines, 10150 kHz: 12069 dB μ V/m QP Conducted emissions conforming to EN/IEC 55011 power lines, 1.530 MHz: 63 dB μ V/m QP Radiated emissions conforming to EN/IEC 55011 class A 10 m, 30230 MHz: 40 dB μ V/m QP Conducted emissions conforming to EN/IEC 55011 power lines, 1501500 kHz: 7963 dB μ V/m QP Radiated emissions conforming to EN/IEC 55011 class A 10 m, 2001000 MHz: 47 dB μ V/m QP
Immunity to microbreaks	10 ms
Ambient air temperature for operation	-1055 °C for horizontal installation -1035 °C for vertical installation
Ambient air temperature for storage	-2570 °C
Relative humidity	1095 % without condensation in operation 1095 % without condensation in storage
IP degree of protection	IP20 with protective cover in place
Pollution degree	<= 2
Operating altitude	02000 m
Storage altitude	03000 m
Vibration resistance	3.5 mm (vibration frequency: 58.4 Hz) on symmetrical rail 1 gn (vibration frequency: 8.4150 Hz) on symmetrical rail 3.5 mm (vibration frequency: 58.4 Hz) on panel mounting 1 gn (vibration frequency: 8.4150 Hz) on panel mounting
Shock resistance	98 m/s² (test wave duration:11 ms)
Offer Sustainability	
Sustainable offer status	Green Premium product

Green Premium product	
Compliant - since 1415 - Schneider Electric declaration of conformity	
Schneider Electric declaration of conformity	
Reference not containing SVHC above the threshold	
Reference not containing SVHC above the threshold	
Available	
Product environmental	
Available	
☑ End of life manual	
	Compliant - since 1415 - Schneider Electric declaration of conformity Schneider Electric declaration of conformity Reference not containing SVHC above the threshold Reference not containing SVHC above the threshold Available Product environmental Available